

Opt Soc Am B. Author manuscript; available in PMC 2009 September 8.

Published in final edited form as:

J Opt Soc Am B. 2008 January 1; 25(12): 2021–2028. doi:10.1364/JOSAB.25.002021.

Effective-substrate theory for optical reflection from a layered substrate

J. P. Landry, **X. Wang**, **Y.Y. Fei**, and **X.D. Zhu***

Department of Physics, University of California at Davis, Davis, CA 95616, USA

Abstract

We show that reflection of a monochromatic light from a semi-infinite medium covered with a stack of layered media is equivalent to that from an effective "semi-infinite medium" characterized by two distinctive optical dielectric constants for the s-polarized and p-polarized components, respectively. Such an effective-substrate approach simplifies the analysis of ellipsometry measurements of a wide range of surface-bound processes including thin film growth and surface-bound reactions.

I. Introduction

Optical reflection techniques such as ellipsometry [1-6], surface plasmon polariton wave excitation [7-11], spectral interferometry [12-14], reflection anisotropy spectroscopy [15,16] and surface photo-absorption [17], are widely used to monitor processes at surfaces and interfaces of solids. They are desirable for versatility, non-invasiveness, and ease of implementation. There exist extensive theoretical studies that link optical reflection to physical and chemical characteristics of solid surfaces and thin films [18-24]. Though optical wavelengths are much larger than the atomic scale, optical reflection contains remarkable amount of information on atomic-scale structures and compositions of a surface (or a thin film) in directions parallel as well as perpendicular to the surface [23]. As a result optical reflection measurements have been used for both qualitative and quantitative studies of surface processes such as surface-bound reactions and epitaxial growths of thin films [1-32].

A surface-bound process causes changes in structure such as thickness or composition of structural components (e.g., terraces, step edges, mounds) and chemical make-up. These changes alter optical reflection through the dielectric responses of altered constituents of the surface. Often one is interested in changes in the top-most layer of a surface or a thin film. Such a layer of atomic scale may reside on top of a semi-infinite substrate or a stack of films (multi-layers) on a semi-infinite substrate. It is desirable to relate changes in the top-most layer to suitably performed optical reflection measurements in a form that enables convenient analysis and exploration of how a stack of multi-layers may enhance the optical response of the topmost layer.

In this paper we show that optical reflection of a monochromatic light from a stack of multilayer films on top of a semi-infinite medium is equivalent to that of another semi-infinite

medium characterized by two effective optical constants, $\varepsilon_{s,\text{eff}}^{(s)}$ and $\varepsilon_{s,\text{eff}}^{(p)}$, for s-polarized and p-polarized components, respectively. The effective optical constants are relatively simple functions of optical and structural properties of the multi-layers and the original semi-infinite medium, and of the incidence angle. Such an effective-substrate approach simplifies the

^{*}E-mail: xdzhu@physics.ucdavis.edu.

analysis of optical reflection from multilayer systems often encountered in studies of surface reactions and thin film growth [23,24].

II. Background on optical reflection from a surface

As shown in Fig. 1, let $\mathbf{r}^{(p)} = |\mathbf{r}^{(p)}| \exp(i\Phi^{(p)})$ and $\mathbf{r}^{(s)} = |\mathbf{r}^{(s)}| \exp(i\Phi^{(s)})$ be the reflectivity (reflection coefficient) for p- and s-polarized components of a monochromatic light off a substrate covered with an ultrathin layer with thickness d and optical constant ε_d , and $\mathbf{r}^{(p0)} = |\mathbf{r}^{(p0)}| \exp(i\Phi^{(p0)})$ and $\mathbf{r}^{(s0)} = |\mathbf{r}^{(s0)}| \exp(i\Phi^{(s0)})$ be the reflectivity from the bare substrate. One can define the oblique-incidence reflectivity difference (OI-RD) as [6,19,23]

$$\Delta_{p} - \Delta_{s} \equiv \delta Ln \left(\frac{r(p)}{r^{(s)}} \right) = \frac{\left| r^{(p)} \right| - \left| r^{(p0)} \right|}{\left| r^{(p0)} \right|} - \frac{\left(\left| r^{(s)} \right| - \left| r^{(s0)} \right| \right)}{\left| r^{(s0)} \right|} + i \left[\left(\Phi^{(p)} - \Phi^{(p0)} \right) - \left(\Phi^{(s)} - \Phi^{(s0)} \right) \right]. \tag{1}$$

Such a difference vanishes at normal incidence. In the present paper, except for the notation of oblique-incidence reflectivity difference $\Delta_p - \Delta_s$, we will use subscripts to keep track of the media in order of their appearance and use superscripts to indicate polarizations. When the substrate is a semi-infinite homogeneous medium with optical constant ϵ_s , the oblique-incidence reflectivity difference (OI-RD) can be expressed as [6,23]

$$\Delta_{\rm p} - \Delta_{\rm s} \cong \left[(-i) \frac{4\pi \cos\varphi_0 \sin^2\varphi_0 \sqrt{\varepsilon_0 \varepsilon_{\rm s}}}{\lambda (\varepsilon_{\rm s} - \varepsilon_0) \left(\varepsilon_{\rm s} \cos^2\varphi_0 - \varepsilon_0 \sin^2\varphi_0 \right)} \right] \frac{(\varepsilon_{\rm d} - \varepsilon_0) (\varepsilon_{\rm d} - \varepsilon_{\rm s})}{\varepsilon_{\rm d}} d$$
(2)

Fei and coworkers extended Eq. (2) to allow the substrate to consist of a uniform layer with optical constant ε_2 and arbitrary thickness d_2 on top of the semi-infinite medium with ε_s [24]. They found that the optical response of such a "composite" substrate could be represented by that of an effective semi-infinite medium characterized by a *single* effective optical constant $\varepsilon_{s,eff}$ such that Eq. (2) remains essentially in tact,

$$\Delta_{p} - \Delta_{s} \cong \alpha_{eff} \frac{(\varepsilon_{d} - \varepsilon_{0}) (\varepsilon_{d} - \varepsilon_{s,eff})}{\varepsilon_{d}} d$$
(3)

The effective optical constant $\varepsilon_{s,eff}$ depends on ε_0 , ε_2 , d_2 , ε_s , and the incidence angle ϕ_0 (see Eq. (A5) in Ref. 24). The pre-factor α_{eff} in Eq. (3), given by Eq. (A6) in Ref. 24, has a much more complex dependence on ε_0 , ε_2 , d_2 , ε_s , and ϕ_0 than that in Eq. (2). This extension made by Fei and coworkers is most useful when analyzing the topmost surface of a thin film during epitaxial growth, particularly when d_2 is no longer small compared to optical wavelengths.

Though a significant step forward, it is difficult to extend the approach of Fei $\it{et~al.}$ to optical reflection from an ultrathin layer on top of a stack of multilayers on a semi-infinite medium. It is also difficult to see how α_{eff} physically depends on the effective optical constant of the effective semi-infinite medium and particularly whether there exist incidence angles that enhance α_{eff} as the Brewster angle does on a semi-infinite medium.

By using a different algebraic approach, we intend to show that (1) reflection of a monochromatic light from a stack of more than one layers on a semi-infinite medium can be

represented by that of an effective semi-infinite medium characterized by two effective optical constants: $\varepsilon_{s,\text{eff}}^{(s)}$ for the s-polarized component and $\varepsilon_{s,\text{eff}}^{(p)}$ for the p-polarized component; (2) Eq. (2) remains valid for an ultrathin surface layer added on top of such an effective medium except

that $\varepsilon_{s,eff}$ is now an algebraic function of $\varepsilon_{s,eff}^{(s)}$ and $\varepsilon_{s,eff}^{(p)}$; (3) there exists an effective Brewster angle (polarizing angle) at which the magnitude of α_{eff} is maximally enhanced. This approach greatly simplifies the analysis of optical reflection for useful information on the topmost layer and how the information can be optimally extracted.

III. Effective-substrate approach to optical reflection from a stack of multilayers on a semi-infinite medium

Although one can resort to numerical computation of optical reflection from a topmost surface layer on an arbitrary multiple-layer stack over a semi-infinite medium using software packages, the numerical approach lacks the transparency of physical insight into the effect of the topmost layer on optical reflection and how a "composite" substrate instead of a simple homogenous semi-infinite substrate alters such the effect in a controllable fashion.

The goals of our algebraic approach are two-fold: (1) to explore whether the reflection from a stack of more than one layer on a homogenous semi-infinite medium can be made equivalent to that from an effective homogenous medium if suitable effective optical constants are introduced; (2) to further explore whether the oblique-incidence reflectivity difference can still be expressed by Eq. (3), and if so, whether α_{eff} contains a similar dependence on incidence angle as in Eq. (2).

We begin with a two-medium model consisting of a semi-infinite ambient with $\varepsilon_0 = n_0^2$ and a semi-infinite substrate with $\varepsilon_s = n_s^2$ as illustrated in Fig. 2a.

A monochromatic light at vacuum wavelength λ is incident from the ambient onto the surface of the substrate at angle ϕ_0 . We first consider the reflection of the s-polarized component. The reflectivity is given by

$$\mathbf{r}_{0s}^{(s)} = \frac{\mathbf{n}_0 \mathbf{cos} \varphi_0 - \mathbf{n}_s \mathbf{cos} \varphi_s}{\mathbf{n}_0 \mathbf{cos} \varphi_0 + \mathbf{n}_s \mathbf{cos} \varphi_s} \tag{4}$$

where ϕ_s is determined from Snell's law $n_s \sin \phi_s = n_0 \sin \phi_0$. When a uniform layer with $\varepsilon_1 = n_1^2$ and an arbitrary thickness d_1 is added between the two semi-infinite media (Fig. 2b), the reflectivity for the s-polarized light is altered and can be calculated as follows

$$r_{01s}^{(s)} = \frac{r_{01}^{(s)} + r_{1s}^{(s)} e^{i\Psi_1}}{1 + r_{01}^{(s)} r_{1s}^{(s)} e^{i\Psi_1}}$$
(5)

where

$$r_{ab}^{(s)} = \frac{n_a \cos\varphi_a - n_b \cos\varphi_b}{n_a \cos\varphi_a + n_b \cos\varphi_b}$$
(6)

$$\Psi_1 = \frac{4\pi n_1 d_1 \cos \varphi_1}{\lambda} \tag{7}$$

 ϕ_1 is determined from $n_1 \sin \phi_1 = n_0 \sin \phi_0$. We now introduce an effective optical constant for the s-polarized light, $\varepsilon_{s,eff}^{(s)}(1,s) = \left(n_{s,eff}^{(s)}(1,s)\right)^2$, such that

$$n_{s,\text{eff}}^{(s)}(1,s)\sin\varphi_{s,\text{eff}}^{(s)}(1,s) = n_0\sin\varphi_0$$
(8)

$$\mathbf{r}_{01s}^{(s)} \equiv \mathbf{r}_{0s,\text{eff}}^{(s)}(1,s) \equiv \frac{\mathbf{n}_{0}\text{cos}\varphi_{0} - \mathbf{n}_{s,\text{eff}}^{(s)}(1,s)\cos\varphi_{s,\text{eff}}^{(s)}(1,s)}{\mathbf{n}_{0}\text{cos}\varphi_{0} + \mathbf{n}_{s,\text{eff}}^{(s)}(1,s)\cos\varphi_{s,\text{eff}}^{(s)}(1,s)}$$
(9)

We use a set of numbers and letters in parentheses to indicate the added layer and the substrate and the order of their appearance for which the effective optical constants and the corresponding angles of transmission are defined. We solve Eq. (9) for $\varepsilon_{s,eff}^{(s)}(1,s)$ with Eq. (5) and Eq. (8),

$$\varepsilon_{\text{s,eff}}^{(s)}(1,s) = n_0^2 \sin^2 \varphi_0 + n_1^2 \cos^2 \varphi_1 \left(\frac{1 - r_{1s}^{(s)} e^{i\Psi_1}}{1 + r_{1s}^{(s)} e^{i\Psi_1}} \right)^2$$
(10)

It is clear from Eq. (10) that $\mathcal{E}_{s,\text{eff}}^{(s)}(1,s)$ depends on properties of the added layer and the original substrate as expected. $\mathcal{E}_{s,\text{eff}}^{(s)}(1,s)$ also depends on the property of the ambient but only through Snell's law or $n_0 \sin \phi_0$. The latter does not change as more layers are added to the substrate subsequently. Eq. (8) through Eq. (10) confirm that the reflection of the s-polarized light from a system of ambient(0)-layer(1)-substrate(s) is equivalent to the reflection from a system of ambient(0)-effective substrate(s, eff) characterized by $\mathcal{E}_{s,\text{eff}}^{(s)}(1,s)$.

This algebraic strategy can be readily extended to a system with m layers covering the substrate so that the reflection from such a stack of multi-layers on a semi-infinite substrate can be replaced by the reflection from an effective substrate characterized by

 $\varepsilon_{s,\text{eff}}^{(s)}$ (m, m – 1, · · · , 1, s). For example, for a system of ambient(0)-layer(2)-layer(1)-substrate (s) as illustrated in Fig. 2c, we define $\varepsilon_{s,\text{eff}}^{(s)}(2,1,s) \equiv \left(n_{s,\text{eff}}^{(s)}(2,1,s)\right)^2$ such that the Snell's law remains valid and the reflectivity has the familiar form,

$$n_{s,eff}^{(s)}(2,1,s)\sin\varphi_{s,eff}^{(s)}(2,1,s) = n_0\sin\varphi_0$$
 (11)

$$\mathbf{r}_{0s,\text{eff}}^{(s)}(2,1,s) = \frac{\mathbf{n}_{0}\cos\varphi_{0} - \mathbf{n}_{s,\text{eff}}^{(s)}(2,1,s)\cos\varphi_{s,\text{eff}}^{(s)}(2,1,s)}{\mathbf{n}_{0}\cos\varphi_{0} + \mathbf{n}_{s,\text{eff}}^{(s)}(2,1,s)\cos\varphi_{s,\text{eff}}^{(s)}(2,1,s)}$$
(12)

Solving Eq. (11) and Eq. (12), we find

$$\varepsilon_{\text{s,eff}}^{(s)}(2,1,s) = n_0^2 \sin^2 \varphi_0 + n_2^2 \cos^2 \varphi_2 \left(\frac{1 - r_{21s}^{(s)} e^{i\Psi_2}}{1 + r_{21s}^{(s)} e^{i\Psi_2}} \right)^2 = n_0^2 \sin^2 \varphi_0 + n_2^2 \cos^2 \varphi_2 \left(\frac{1 - r_{2s,\text{eff}}^{(s)}(1,s) e^{i\Psi_2}}{1 + r_{2s,\text{eff}}^{(s)}(1,s) e^{i\Psi_2}} \right)^2$$

$$(13)$$

with

$$r_{21s}^{(s)} \equiv r_{2s,\text{eff}}^{(s)}(1,s) \equiv \frac{n_2 \text{cos}\varphi_2 - n_{s,\text{eff}}^{(s)}(1,s) \cos\varphi_{s,\text{eff}}^{(s)}(1,s)}{n_2 \text{cos}\varphi_2 + n_{s,\text{eff}}^{(s)}(1,s) \cos\varphi_{s,\text{eff}}^{(s)}(1,s)}$$
(14)

with $n_{s,eff}^{(s)}(1,s)$ and $\varphi_{s,eff}^{(s)}(1,s)$ are given by Eq. (10) and Eq. (8).

For a system of ambient(0)-layer(m)-layer(m-1)- ···-layer(1)-substrate, we can generally define and find an effective optical dielectric constant for the s-polarized light,

 $\varepsilon_{s,\text{eff}}^{(s)}(m,m-1,\cdots,1,s) \equiv \varepsilon_{s,\text{eff}}^{(s)} = \left(n_{s,\text{eff}}^{(s)}\right)^2$, such that the reflection from such a system is given by

$$r_{0s,\text{eff}}^{(s)}(m, m-1, \cdots, 1, s) = \frac{n_0 \cos \varphi_0 - n_{s,\text{eff}}^{(s)} \cos \varphi_{s,\text{eff}}^{(s)}}{n_0 \cos \varphi_0 + n_{s,\text{eff}}^{(s)} \cos \varphi_{s,\text{eff}}^{(s)}}$$
(15)

$$n_{s,eff}^{(s)} \sin \varphi_{s,eff}^{(s)} = n_0 \sin \varphi_0$$
(16)

Here $\varepsilon_{s,\text{eff}}^{(s)}(m, m-1, \dots, 1, s)$ is found iteratively using the following equations,

$$\varepsilon_{s,\text{eff}}^{(s)}(m, m-1, \cdots, 1, s) = n_0^2 \sin^2 \varphi_0 + n_m^2 \cos^2 \varphi_m \left(\frac{1 - r_{ms,\text{eff}}^{(s)}(m-1, \cdots, 1, s) e^{i\Psi_m}}{1 + r_{ms,\text{eff}}^{(s)}(m-1, \cdots, 1, s) e^{i\Psi_m}} \right)^2$$
(17)

$$r_{\text{ms,eff}}^{(s)}(m-1,\cdots,1,s) = \frac{n_{\text{m}}\cos\varphi_{\text{m}} - n_{\text{s,eff}}^{(s)}(m-1,\cdots,1,s)\cos\varphi_{\text{s,eff}}^{(s)}(m-1,\cdots,1,s)}{n_{\text{m}}\cos\varphi_{\text{m}} + n_{\text{s,eff}}^{(s)}(m-1,\cdots,1,s)\cos\varphi_{\text{s,eff}}^{(s)}(m-1,\cdots,1,s)}$$
(18)

This process is repeated until Eq. (17) is reduced to Eq. (10).

We now apply the similar procedure for the p-polarized component. For a two-medium system as illustrate in Fig. 2a, the reflectivity for the p-polarized light is given by

$$r_{0s}^{(p)} = \frac{n_0 \cos\varphi_s - n_s \cos\varphi_0}{n_0 \cos\varphi_s + n_s \cos\varphi_0}$$
(19)

where $n_s \sin \phi_s = n_0 \sin \phi_0$. When a uniform layer with $\varepsilon_1 = n_1^2$ and an arbitrary thickness d_1 is added between the two semi-infinite media (Fig. 2b), the reflectivity for the p-polarized light is altered to

$$r_{01s}^{(p)} = \frac{r_{01}^{(p)} + r_{1s}^{(p)} e^{i\Psi_1}}{1 + r_{01}^{(p)} r_{1s}^{(p)} e^{i\Psi_1}}$$
(20)

where Ψ_1 is given by Eq. (7),

$$r_{ab}^{(p)} = \frac{n_a \cos\varphi_b - n_b \cos\varphi_a}{n_a \cos\varphi_b + n_b \cos\varphi_a}, \tag{21}$$

and $n_1 \sin \phi_1 = n_0 \sin \phi_0$. We now introduce an effective optical constant for the p-polarized light, $\varepsilon_{s, \text{eff}}^{(p)}(1, s) = \left(n_{s, \text{eff}}^{(p)}(1, s)\right)^2$, such that

$$n_{s,eff}^{(p)}(1,s)\sin\varphi_{s,eff}^{(p)}(1,s) = n_0\sin\varphi_0$$
 (22)

$$\mathbf{r}_{01s}^{(p)} \equiv \mathbf{r}_{0s,\text{eff}}^{(p)} \equiv \frac{n_0 \cos \varphi_{s,\text{eff}}^{(p)}(1,s) - n_{s,\text{eff}}^{(p)}(1,s) \cos \varphi_0}{n_0 \cos \varphi_{s,\text{eff}}^{(p)}(1,s) + n_{s,\text{eff}}^{(p)}(1,s) \cos \varphi_0}$$
(23)

Solving Eq. (23) for $\varepsilon_{s,eff}^{(p)}(1,s)$ together with Eq. (20) and Eq. (22), we arrive at

$$\frac{\varepsilon_{s,\text{eff}}^{(p)}(1,s)}{\left(\frac{n_1^2}{\cos^2\varphi_1}\right)\left(\frac{1-r_{1s}^{(p)}e^{i\Psi_1}}{1+r_{1s}^{(p)}e^{i\Psi_1}}\right)^2} + \frac{n_0^2\sin^2\varphi_0}{\varepsilon_{s,\text{eff}}^{(p)}(1,s)} = 1$$
(24)

 $\varepsilon_{s,\text{eff}}^{(p)}(1,s)$ is a function of properties of the added layer and the original semi-infinite substrate and only depends on the property of the ambient through $n_0 \sin \phi_0$. As a result the reflection

for p-polarized light from a system of ambient(0)-layer(1)-substrate(s) is equivalently replaced by the reflection from a system of ambient(0)-effective substrate(s, eff) characterized by $\varepsilon_{s,\text{eff}}^{(p)}(1,s).$

Such a strategy is easily extended to the reflection from a system of ambient(0)-layer(m)-layer (m-1)-···-layer(1)-substrate by repeating the aforementioned steps to define and find an

effective optical constant for p-polarized light $\varepsilon_{s,\text{eff}}^{(p)}(m,m-1,\cdots,1,s) \equiv \varepsilon_{s,\text{eff}}^{(p)} = \left(n_{s,\text{eff}}^{(p)}\right)^2$ so that the reflection from such a system is given by

$$r_{0s,\text{eff}}^{(p)}(m, m-1, \cdots, 1, s) = \frac{n_0 \cos \varphi_{s,\text{eff}}^{(s)} - n_{s,\text{eff}}^{(s)} \cos \varphi_0}{n_0 \cos \varphi_{s,\text{eff}}^{(s)} + n_{s,\text{eff}}^{(s)} \cos \varphi_0}$$
(25)

$$n_{s,ff}^{(p)}\sin\varphi_{s,ff}^{(p)} = n_0\sin\varphi_0 \tag{26}$$

Here $\varepsilon_{s,eff}^{(p)}(m,m-1,\cdots,1,s)$ is given by

$$\frac{\varepsilon_{s,\text{eff}}^{(p)}(m,m-1,\dots,1,s)}{\left(\frac{n_{m}^{2}}{\cos^{2}\varphi_{m}}\right)\left(\frac{1-r_{ms,\text{eff}}^{(p)}(m-1,\dots,1,s)}{1+r_{ms,\text{eff}}^{(p)}(m-1,\dots,1,s)}e^{i\Psi_{m}}\right)^{2}} + \frac{n_{0}^{2}\sin^{2}\varphi_{0}}{\varepsilon_{s,\text{eff}}^{(p)}(m,m-1,\dots,1,s)} = 1$$
(27)

$$r_{ms,eff}^{(p)}(m-1,\cdots,1,s) \equiv \frac{n_{m}cos\varphi_{s,eff}^{(p)}(m-1,\cdots,1,s) - n_{s,eff}^{(p)}(m-1,\cdots,1,s)cos\varphi_{m}}{n_{m}cos\varphi_{s,eff}^{(p)}(m-1,\cdots,1,s) + n_{s,eff}^{(p)}(m-1,\cdots,1,s)cos\varphi_{m}}$$
(28)

Again this process is repeated until Eq. (27) is reduced to Eq. (24).

To briefly summarize, we have shown that optical reflection for a monochromatic light beam from a stack of multi-layers on top of a semi-infinite substrate can be reduced to reflection of the same beam from an effective semi-infinite substrate with two distinctive optical constants for s-polarized and p-polarized components, respectively. The two optical constants depend on the incidence angle in the ambient through Snell's law, and can be found iteratively. One can easily show that when the thicknesses of the multi-layers are taken to zero, the effective optical constants for both s- and p-polarized components are reduced to ϵ_s .

IV. Oblique-incidence reflectivity difference due to an ultrathin surface layer on top of a stack of multi-layers on a homogeneous semi-infinite substrate

We compute the fractional change in reflectivity for both polarizations when an ultrathin layer with thickness $d \ll \lambda$ and optical constant ϵ_d is added between the ambient with ϵ_0 and the effective substrate with $\epsilon_{s,eff}^{(p)}$ and $\epsilon_{s,eff}^{(s)}$, as illustrated in Fig. 3.

For the s-polarized component of the incident light, the reflectivity before and after the addition of the extra layer are

$$r_{0s,eff}^{(s)} = \frac{n_0 \cos \varphi_0 - n_{s,eff}^{(s)} \cos \varphi_{s,eff}^{(s)}}{n_0 \cos \varphi_0 + n_{s,eff}^{(s)} \cos \varphi_{s,eff}^{(s)}}$$
(29)

$$r_{0ds,eff}^{(s)} = \frac{r_{0d}^{(s)} + r_{ds,eff}^{(s)} e^{i\Psi_d}}{1 + r_{0d}^{(s)} r_{ds,eff}^{(s)} e^{i\Psi_d}}$$
(30)

with $n_d \sin \phi_d = n_0 \sin \phi_0$ and

$$r_{ds,eff}^{(s)} = \frac{n_d \cos\varphi_d - n_{s,eff}^{(s)} \cos\varphi_{s,eff}^{(s)}}{n_d \cos\varphi_d + n_{s,eff}^{(s)} \cos\varphi_{s,eff}^{(s)}}$$
(31)

$$r_{0d}^{(s)} = \frac{n_0 \cos\varphi_0 - n_d \cos\varphi_d}{n_0 \cos\varphi_0 + n_d \cos\varphi_d}$$
(32)

$$\Psi_{\rm d} = \frac{4\pi n {\rm d} {\rm d} {\rm cos} \varphi_{\rm d}}{\lambda} \tag{33}$$

The differential reflectivity for the s-polarized component can be derived from Eq. (29) through Eq. (33) and is given by

$$\Delta_{s} \equiv \frac{r_{0ds,eff}^{(s)} - r_{0s,eff}^{(s)}}{r_{0s,eff}^{(s)}} \cong \frac{\left(\varepsilon_{d} - \varepsilon_{s,eff}^{(s)}\right)}{\left(\varepsilon_{0} - \varepsilon_{s,eff}^{(s)}\right)} \left(\frac{i4\pi n_{0}\cos\varphi_{0}}{\lambda}\right) d \tag{34}$$

where we only keep the term that varies linearly with d/λ .

For the p-polarized component of the incident light, the reflectivity before and after adding the extra layer are given by the following expressions,

$$r_{0s,\text{eff}}^{(p)} = \frac{n_0 \cos \varphi_{s,\text{eff}}^{(p)} - n_{s,\text{eff}}^{(p)} \cos \varphi_0}{n_0 \cos \varphi_{s,\text{eff}} + n_{s,\text{eff}}^{(p)} \cos \varphi_0}$$
(35)

$$r_{\text{0ds,eff}}^{(p)} = \frac{r_{\text{0d}}^{(p)} + r_{\text{ds,eff}}^{(p)} e^{i\Psi_{\text{d}}}}{1 + r_{\text{0d}}^{(p)} r_{\text{ds,eff}}^{(p)} e^{i\Psi_{\text{d}}}}$$
(36)

with Ψ_d given by Eq. (33) and

$$r_{ds,eff}^{(p)} = \frac{n_d \cos\varphi_{s,eff}^{(p)} - n_{s,eff}^{(p)} \cos\varphi_d}{n_d \cos\varphi_{s,eff}^{(p)} + n_{s,eff}^{(p)} \cos\varphi_d}$$
(37)

$$r_{0d}^{(p)} = \frac{n_0 \cos\varphi_d - n_d \cos\varphi_0}{n_0 \cos\varphi_d + n_d \cos\varphi_0}$$
(38)

From Eq. (35) through Eq. (38), we find the differential reflectivity for the p-polarized component,

$$\Delta_{p} \equiv \frac{r_{0ds,eff}^{(p)} - r_{0s,eff}^{(p)}}{r_{0s,eff}^{(p)}} \cong \left[\frac{\left(\left(\varepsilon_{d} + \varepsilon_{s,eff}^{(p)} \right) \varepsilon_{0} \sin^{2} \varphi_{0} - \varepsilon_{d} \varepsilon_{s,eff}^{(p)} \right) \left(\varepsilon_{d} - \varepsilon_{s,eff}^{(p)} \right)}{\varepsilon_{d} \left(\varepsilon_{0} \sin^{2} \varphi_{0} - \varepsilon_{s,eff}^{(p)} \cos^{2} \varphi_{0} \right) \left(\varepsilon_{0} - \varepsilon_{s,eff}^{(p)} \right)} \right] \left(\frac{i4\pi n_{0} \cos \varphi_{0}}{\lambda} \right) d$$
(39)

The oblique-incidence reflectivity difference (OI-RD) as defined by Eq. (1) then takes on the same form as Eq. (3),

$$\Delta_{p} - \Delta_{s} \cong \alpha_{eff} \frac{(\varepsilon_{d} - \varepsilon_{0})(\varepsilon_{d} - \varepsilon_{s,eff})}{\varepsilon_{d}} d$$
(40)

with

$$\alpha_{\text{eff}} \cong -\left(\frac{i4\pi n_0 \cos\varphi_0}{\lambda}\right) \frac{\varepsilon_0 \varepsilon_{\text{s,eff}}^{(s)} \sin^2\varphi_0 + \left(\varepsilon_{\text{s,eff}}^{(p)}\right)^2 \cos^2\varphi_0 - \varepsilon_{\text{s,eff}}^{(s)} \varepsilon_{\text{s,eff}}^{(p)}}{\left(\varepsilon_0 - \varepsilon_{\text{s,eff}}^{(p)}\right) \left(\varepsilon_0 - \varepsilon_{\text{s,eff}}^{(s)}\right) \left(\varepsilon_{\text{s,eff}}^{(p)} \cos^2\varphi_0 - \varepsilon_0 \sin^2\varphi_0\right)}$$

$$(41)$$

$$\varepsilon_{\text{s,eff}} \cong \frac{\left(\varepsilon_{\text{s,eff}}^{(p)}\right)^2 \left(\varepsilon_0 - \varepsilon_{\text{s,eff}}^{(s)}\right) \sin^2 \varphi_0}{\varepsilon_0 \varepsilon_{\text{s,eff}}^{(s)} \sin^2 \varphi_0 - \varepsilon_{\text{s,eff}}^{(p)} \left(\varepsilon_{\text{s,eff}}^{(s)} - \varepsilon_{\text{s,eff}}^{(p)} \cos^2 \varphi_0\right)}$$
(42)

It is easily verified that when the thickness of the stack of multi-layers goes to zero, $\varepsilon_{s,eff}$ is reduced to ε_{s} and we regain Eq. (2).

To see that the general results expressed by Eq. (40) through Eq. (42) are reduced to the results reported by Fei and coworkers [24] for a system of ambient(0)-surface layer(d)-layer(1)-substrate(s) as illustrated in Fig. 4, we can rewrite Eq. (41) and Eq. (42) into the following forms with the help of Eq. (10) and Eq. (24),

$$\alpha_{\text{eff}} \simeq -\left(\frac{i4\pi n_0 \cos\varphi_0}{\lambda}\right) \left(\frac{1}{\varepsilon_{\text{s,eff}}^{(s)}(1,s) - \varepsilon_0}\right) \left(\frac{\cos^2\varphi_0 - \varepsilon_{\text{s,eff}}^{(s)}(1,s) \left(\frac{\cos\varphi_1}{n_1}\right)^2 \left(\frac{1 + r_{\text{ls}}^{(p)} e^{i\Psi_1}}{1 - r_{\text{ls}}^{(p)} e^{i\Psi_1}}\right)^2}{\cos^2\varphi_0 - \varepsilon_0 \left(\frac{\cos\varphi_1}{n_1}\right)^2 \left(\frac{1 + r_{\text{ls}}^{(p)} e^{i\Psi_1}}{1 - r_{\text{ls}}^{(p)} e^{i\Psi_1}}\right)^2}\right)$$

$$(43)$$

$$\varepsilon_{\text{s,eff}} \cong \frac{\left(\varepsilon_0 - \varepsilon_{\text{s,eff}}^{(s)}(1, s)\right) \sin^2 \varphi_0}{\cos^2 \varphi_0 - \varepsilon_{\text{s,eff}}^{(s)}(1, s) \left(\frac{\cos \varphi_1}{n_1}\right)^2 \left(\frac{1 + r_{1s}^{(p)} e^{i\Psi_1}}{1 - r_{1s}^{(p)} e^{i\Psi_1}}\right)^2}$$

$$(44)$$

Eq. (43) is the same as Eq. (A6) of Ref. 24 except for the difference in notation. Eq. (44) is the same as Eq. (A7) of Ref. 24 except for notation.

Eq. (40) through Eq. (44) together with Eq. (10) and Eq. (24) are the main results of this paper. We emphasize that optical constants $\varepsilon_{s,\text{eff}}^{(p)}$ and $\varepsilon_{s,\text{eff}}^{(s)}$ of the effective substrate are functions of the incidence angle φ_0 as well as the properties of its constituents. As φ_0 changes, $\varepsilon_{s,\text{eff}}^{(p)}$ and $\varepsilon_{s,\text{eff}}^{(s)}$ need to be computed again.

V. Discussion

We discuss the key features of the present effective-substrate model and the significance of such a general approach to optical reflection from a multi-layer stack on a semi-infinite substrate.

It is remarkable that given the incidence angle from an ambient, the reflectivity from an arbitrary stack of multilayers on top of a semi-infinite substrate can always be represented by the reflectivity from an effective substrate characterized by two complex optical constants, one for the s-polarized component and the other for the p-polarized component.

It is equally remarkable that the oblique-incidence reflectivity difference (OI-RD) due to the presence or addition of an ultrathin layer on top of the effective substrate has the same form as that for the ultrathin layer on top of a homogeneous semi-infinite substrate. Only in this case

the effective optical constant $\epsilon_{s,eff}$ is an algebraic function of $\epsilon_{s,eff}^{(p)}$ and $\epsilon_{s,eff}^{(s)}$ (prescribed by Eq.

(42) or Eq. (44)), and the pre-factor α_{eff} is also an algebraic function of $\varepsilon_{s,eff}^{(p)}$ and $\varepsilon_{s,eff}^{(s)}$ (prescribed by Eq. (41) or Eq. (43)). Compared to the theory reported by Fei and coworkers [24], we have now generalized Eq. (40) to an ultrathin film on top of an arbitrary stack of multi-layers on a homogeneous, semi-infinite substrate. This makes the present model applicable to practically all cases of thin films growth and surface reactions when the light is incident from the ambient.

The factorized form of Eq. (41) reveals explicitly how the pre-factor α_{eff} in Eq. (40) varies with the incidence angle and the dielectric properties of the ambient and the effective substrate.

 α_{eff} has three poles: $\varepsilon_{s,eff}^{(p)} = \varepsilon_0$, $\varepsilon_{s,eff}^{(s)} = \varepsilon_0$, and $\varepsilon_{s,eff}^{(p)} = \varepsilon_0 \tan^2 \varphi_0$. The latter is equivalent to the pole in Eq. (2) associated with the Brewster angle (the polarizing angle). Since the Brewster angle is only associated with the p-polarized component of an incident light, it is physically sensible and reassuring that an effective Brewster angle for the effective substrate exists and is determined only by the effective optical constant for the p-polarized component,

 $\varepsilon_{s,\text{eff}}^{(p)}\cos^2\varphi_0=\varepsilon_0\sin^2\varphi_0$. The poles in α_{eff} are useful in practice because the magnitude of $\Delta_p-\Delta_s$ in response to the ultrathin surface layer can be enhanced at or near these poles, as pointed by Landry and coworkers [33]. At the interface between two semi-infinite homogeneous media, the only practical pole is the Brewster angle determined by $\varepsilon_s\cos^2\varphi_{0B}=\varepsilon_0\sin^2\varphi_{0B}$. At the interface between a homogeneous ambient and an effective substrate consisting of a multilayer stack on a semi-infinite homogeneous medium, we have three usable poles if suitable choices of thickness and optical dielectric properties of the multilayers are made.

The present theory of oblique-incidence optical reflectivity difference is significant as it covers essentially all systems encountered in thin film growths and surface reactions. During a film growth or surface reactions on functionalized or modified substrates, one often deals with a top-most surface layer on top of another layer (on a homogeneous substrate) whose structural and electronic properties may vary along the surface normal, either by design or as a result of the kinetic process. When the thickness of the intervening layer is no longer small compared to the optical wavelength and the optical dielectric response of the layer cannot be adequately described by averaging the optical constant along the surface normal, one needs to treat the layer as a stack of multilayers each of which has its distinct optical constant and thickness [24,34-36]. The present theory offers an analytical way to treat such an intervening layer by introducing an effective substrate and thus simplifies the physical analysis of oblique-incidence reflectivity difference. Since one of the objectives of optical reflection measurement is to determine the property of the topmost surface layer during a surface-bound process, an intervening layer may be utilized to enhance the net optical response of the surface layer by making α_{eff} close to one of the poles or to enhance the contrast of the ellipsometric detection by making $\varepsilon_{s,eff}$ (given by Eq. (42) or (44)) close to ε_d so that minute changes in ε_d during the subsequent kinetic process are readily observable.

VI. Conclusion

We developed an effective-substrate theory to treat optical reflection from a stack of multilayer on a homogeneous semi-infinite substrate. Such a theory simplifies the physical analysis of optical reflection from such a system and the change of it when an ultrathin film (i.e., the surface layer) is added or changed on top of the stack. Within the framework of the effective-substrate theory, the oblique-incidence reflectivity difference (ubiquitously measured in various forms of ellipsometry) maintains a simple, factorized form. There exists a great potential for enhancing the optical response of an ultrathin surface layer with suitably chosen effective substrates.

Acknowledgments

Acknowledgment is made to the Donors of the American Chemical Society Petroleum Research Fund for partial support of this research. The work was also supported by National Institutes of Health under NIH-5-R01-HG003827.

References

- 1. Azzam, RMA.; Bashara, NM. Ellipsometry and Polarized Light. Elsevier Science; New York: 1987.
- 2. Drevillon B. Phase modulated ellipsometry from the ultraviolet to the infrared: in situ application to the growth of semiconductors. Prog Crystal Growth and Charact 1993;27:1–87.

3. Theeten JB, Hottier F, Hallais J. On-time determination of the composition of III-V ternary layers during VPE growth. Appl Phys Lett 1978;32:576–578.

- Bleckmann L, Hunderi O, Richter W, Wold E. Surface studies by means of 45° reflectometry. Surf Sci 1996;351:277–284.
- Dietz N, Sukidi N, Harris C, Bachmann KJ. Real-time monitoring of surface processes by p-polarized reflectance. J Vac Sci Technol 1997;A 15:807–815.
- Thomas P, Nabighian E, Bartelt MC, Fong CY, Zhu XD. An oblique-incidence optical reflectivity difference and LEED study of rare-gas growth on a lattice-mismatched metal substrate. Appl Phys 2004;A 79:131–137.
- Burstein E, Chen WP, Chen YJ, Hartstein A. Surface polaritons propagating electromagnetic modes at interfaces. J Vac Sci Technol 1974;11:1004–1019.
- 8. Holst K, Raether H. The influence of thin surface films on the plasma resonance emmision. Opt Commun 1970;2:312–316.
- Weber WH. Modulated surface-plasmon resonances for in situ metal-film surface studies. Phys Rev Lett 1977;39:153–156.
- Abeles, F.; Lopez-Rios, T. Surface Polaritons: Electromagnetic Waves at Surfaces and Interfaces. Agranovich, VM.; Mills, DL., editors. North-Holland; Amsterdam: 1982. p. 239
- 11. Bhasin K, Bryan D, Alexander RW, Bell RJ. Absorption in the infrared of surface electromagnetic waves by adsorbed molecules on a copper surface. J Chem Phys 1976;64:5019–5025.
- Flournoy PA, McClure RW, Wyntjes G. White –light interferometric tickness gauge. Appl Opt 1972;11:1907–1915.
- Brecht A, Ingenhoff J, Gauglitz G. Direct monitoring of antigen-antibody interactions by spectral interferometry. Sensors and Actuators 1992;B 6:96–100.
- 14. Piehler J, Brecht A, Gauglitz G. Affinity detection of low molecular weight analytes. Anal Chem 1996;68:139–143.
- 15. Aspnes DE. Above-bandgap optical anisotropies in cubic semiconductors: a visible-near ultraviolet probe of surfaces. J Vac Sci Technol 1985;B 3:1498–1506.
- McGilp JF. Optical characterisation of semiconductor surfaces and interfaces. Prog Surf Sci 1995;49:1–106.
- 17. Kobayashi N, Horikoshi Y. Spectral dependence of optical reflectance during flow-rate modulation epitaxy of GaAs by the surface photo-absorption method. Jpn J Appl Phys 1990;29:L702–L705.
- 18. Born, M.; Wolf, W. Principles of Optics. Pergamon Press; Oxford: 1993. p. 51
- 19. McIntyre JDE, Aspnes DE. Differential reflection spectroscopy of very thin surface films. Surf Sci 1971;24:417–434.
- Bruggeman DAG. Berechnung verschiedener physikalischer Konstanten von. heterogenen Substanzen. Ann Phys (Leip) 1935;24:636–664.
- 21. Aspnes DE, Theeten JB, Hottier F. Investigation of effective-medium models of microscopic surface roughness by spectroscopic ellipsometry. Phys Rev 1979;B 20:3292–3302.
- 22. Muller RH, Farmer JC. Macroscopic optical models for the ellipsometry of an under-potential deposit: lead in copper and silver. Surf Sci 1983;135:521–531.
- 23. Zhu XD. Oblique-incidence optical reflectivity difference from a rough film of crystalline material. Phys Rev 2004;B 69:115407-1–5.
- 24. Zhu XD, Fei YY, Wang X, Lu HB, Yang GZ. General theory of optical reflection from a thin film on a solid and its application to heteroepitaxy. Phys Rev 2007;B 75:245434-1–14.
- 25. Jin G, Jansson R, Arwin H. Imaging ellipsometry revisited: developments for visualization of thin transparent layers on silicon substrates. Rev Sci Instrum 1996;67:2930–2936.
- Liedberg B, Nylander C, Lundstrom I. Surface plasmon resonance for gas detection and biosensing. Sensors and Actuators 1983;4:299–304.
- Nelson BP, Frutos AG, Brockman JM, Corn RM. Near-infrared surface plasmon resonance measurements of ultrathin films. 1. angle shift and SPR imaging experiments. Anal Chem 1999;71:3928–3934.
- 28. Shumaker-Parry JS, Campbell CT. Quantitative methods for spatially-resolved adsorption/desorption measurements in real time by SPR microscopy. Anal Chem 2004;76:907–917. [PubMed: 14961720]

29. Zhu XD, Lu HB, Yang GZ, Li ZY, Gu BY, Zhang DZ. Epitaxial growth of SrTiO₃ on SrTiO₃(001) using an oblique-incidence reflectance-difference technique. Phys Rev 1998;B 57:2514–2519.

- 30. Fei YY, Zhu XD, Liu LF, Lu HB, Chen ZH, Yang GZ. Oscillations in oblique-incidence optical reflection from a growth surface during layer-by-layer epitaxy. Phys Rev 2004;B 69:233405-1-4.
- 31. Schwarzacher W, Gray J, Zhu XD. Oblique-incidence reflectivity difference as an in situ probe of Co electrodeposition on polycrystalline Au. Electrochem Solid-State Lett 2003;6:C73–C76.
- 32. Landry JP, Zhu XD, Gregg J. Label-free detection of microarrays of biomolecules using oblique-incidence reflectivity difference microscopy. Opt Lett 2004;29:581–583. [PubMed: 15035477]
- 33. Landry JP, Gray J, O'Toole MK, Zhu XD. Incidence-angle dependence of optical reflectivity difference from an ultrathin film on solid surface. Opt Lett 2006;31:531–533. [PubMed: 16496910]
- 34. Tikhonravov AV, Truetskov MK, Krasilnikova AV. Spectroscopic ellipsometry of slightly inhomogeneous non-absorbing thin films with arbitrary reflective-index profiles: theoretical study. Appl Opt 1998;37:5902–5911. [PubMed: 18286084]
- 35. Adamson P. Reflection of light in a long-wavelength approximation from an N-layer system of inhomogeneous dielectric films and optical diagnostics of ultrathin layers. I. Absorbing substrate. J Opt Soc Am 2003;B 20:752–759.
- 36. Adamson P. Reflection of light in a long-wavelength approximation from an N-layer system of inhomogeneous dielectric films and optical diagnostics of ultrathin layers. II. transparent substrate. J Opt Soc Am 2004;B 21:645–654.

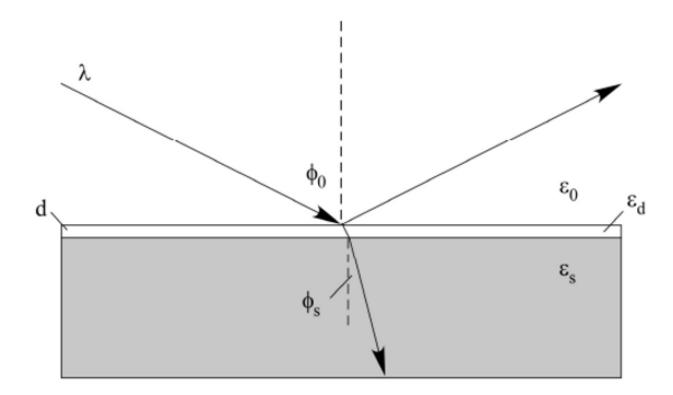
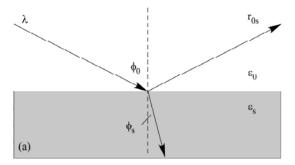
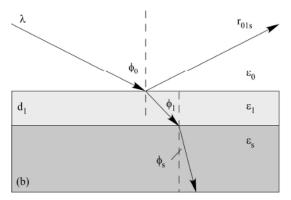
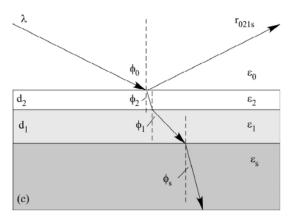


Fig. 1. Reflection of a monochromatic light at vacuum wavelength λ from the surface of a semi-infinite substrate (ϵ_s) covered with an ultrathin layer (ϵ_d) with thickness $d \ll \lambda$. The beam travels in a semi-infinite ambient (ϵ_0) before reflection.







(a) Reflection of a monochromatic light at vacuum wavelength λ from the bare surface of a semi-infinite substrate (ϵ_s) ; (b) reflection from the surface of a semi-infinite substrate (ϵ_s) covered with a uniform dielectric layer (ϵ_1) with arbitrary thickness d_1 ; (c) reflection from the surface of a semi-infinite substrate covered with two uniform dielectric layers $(\epsilon_1$ and $\epsilon_2)$ with arbitrary thicknesses d_1 and d_2 .

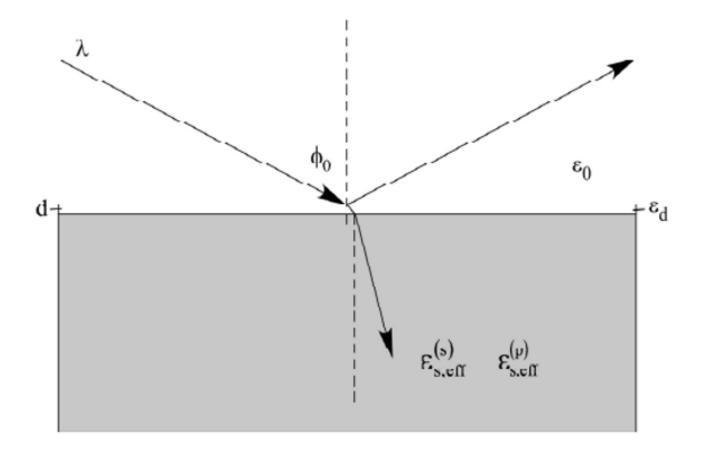


Fig. 3. Reflection from the surface of an effective substrate covered with an ultrathin layer (ε_d) with thickness $d \ll \lambda$. The effective substrate is characterized by two optical constants, $\varepsilon_{s,\text{eff}}^{(p)}$ and $\varepsilon_{s,\text{eff}}^{(s)}$, for the s-polarized and p-polarized components of the incident light.

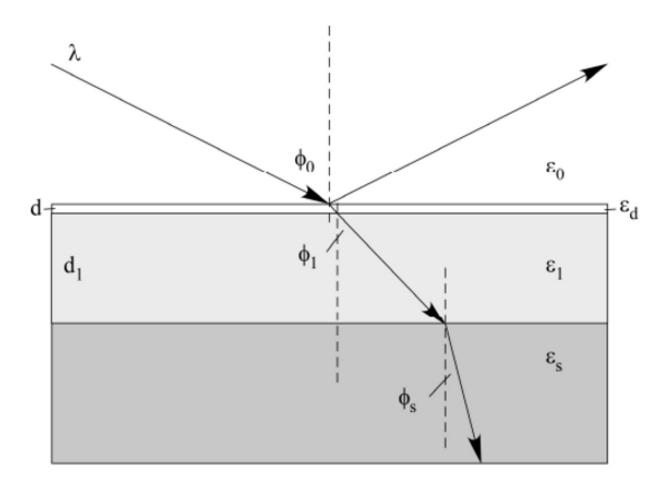


Fig. 4. Reflection from the surface of a semi-infinite substrate covered with an ultrathin film (ϵ_d) with thickness $d \ll \lambda$ and a uniform dielectric layer (ϵ_1) with arbitrary thickness d_1 .